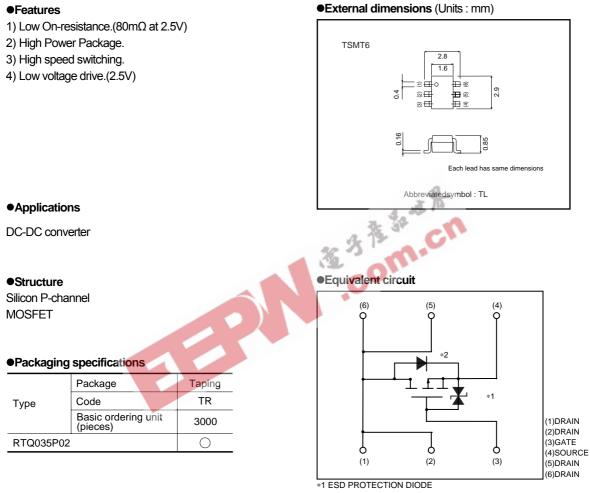
DC-DC Converter (-20V, -3.5A) RTQ035P02



*2 BODY DIODE

Transistor

•Absolute maximum ratings (Ta=25°C)

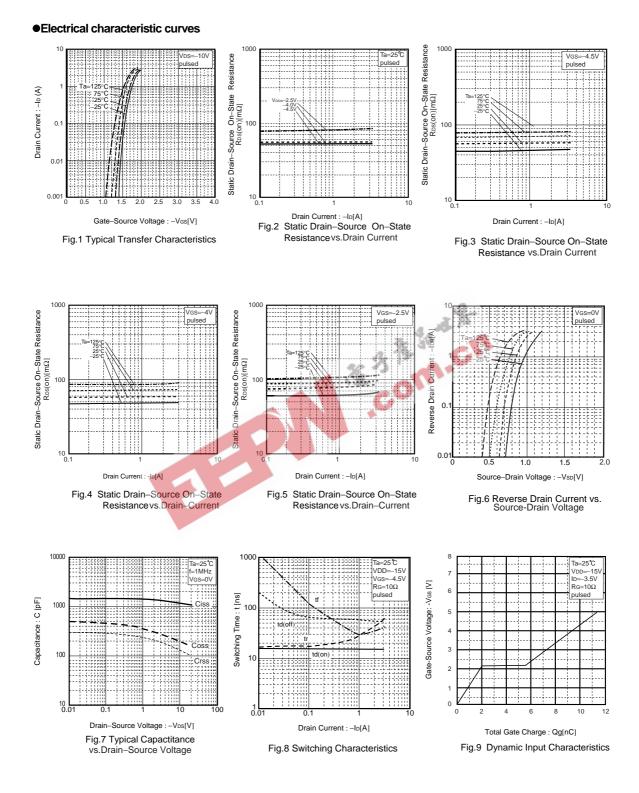
| Parameter | | Symbol Limits | | Unit | |
|--------------------------------|------------|---------------|----------|------|--|
| Drain-source voltage | | Vdss | -20 | V | |
| Gate-source voltage | | Vgss | ±12 | V | |
| Drain current | Continuous | lo | ±3.5 | А | |
| | Pulsed | DP | ±17.5 | A *1 | |
| Source current (Body diode) | Continuous | ls | -1 | А | |
| | Pulsed | ISP | -4 | A *1 | |
| Total power dissipation | | Po | 1.25 | W*2 | |
| Channel temperature | | Tch | 150 | °C | |
| Range of Storage temperature | | Tstg | -55~+150 | °C | |

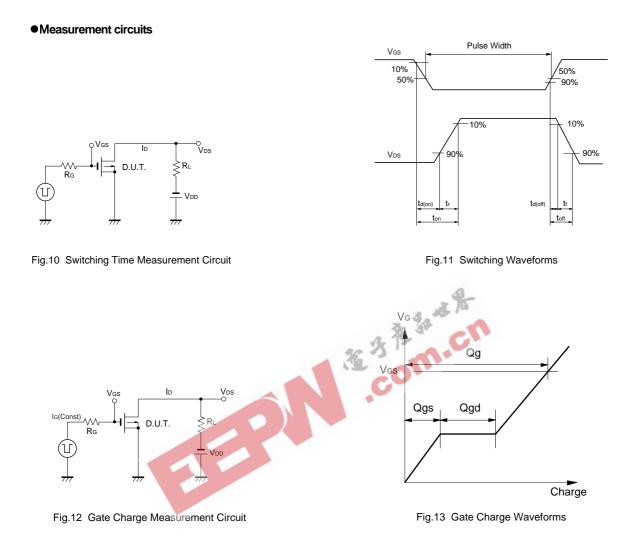
*1 Pw≦10μs, Duty cycle≦1% *2 Mounted on a ceramic board

•Electrical characteristics (Ta=25°C)

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions | | |
|--|--------------------|------|------|------|------|---|--|--|
| Gate-source leakage | lgss | - | - | ±10 | μA | Vgs=±12V, Vds=0V | | |
| Drain-source breakdown voltage | V(BR)DSS | -20 | - | - | V | ID=-1mA, VGS=0V | | |
| Zero gate voltage drain current | IDSS | - | - | -1 | μA | Vps=-20V, Vgs=0V | | |
| Gate threshold voltage | VGS(th) | -0.7 | - | -2.0 | R V | VDs=-10V, ID=-1mA | | |
| | | - | 50 | 65 | mΩ | ID=-3.5A, VGs = -4.5V | | |
| Static drain-source on-state resistance | RDS(on) | | 55 | 70 | mΩ | ID=-3.5A, Vgs=-4V | | |
| resistance | | | 80 | 100 | mΩ | ID=-1.75A, VGs=-2.5V | | |
| Foward transfer admittance | Y _{fs} * | 3.5 | _ | - | S | VDS=-10V, ID=-3.5A | | |
| Input capacitance | Ciss | - | 1200 | - | pF | V _{DS=} –10V,V _{GS} =0V f=1MHz | | |
| Output capacitance | Coss | - | 200 | - | pF | | | |
| Reverse transfer capacitance | Crss | _ | 130 | - | pF | | | |
| Turn-on delay time | td(on) * | - | 16 | - | ns | Ip=-2A | | |
| Rise time | tr * | - | 40 | - | ns | V _{DD} ≕−15V | | |
| Turn-off delay time | td(off) * | - | 55 | - | ns | $\begin{array}{l} V_{GS}=-4.5V\\ R_{L}=7.5\Omega\\ R_{GS}=10\Omega \end{array}$ | | |
| Fall time | tr * | - | 30 | - | ns | | | |
| Total gate charge | Qg | - | 10.5 | - | nC | - V _{DD} ≒–15V Vgs=–4.5V ID=–3.5A | | |
| Gate-source charge | Qgs | _ | 2.0 | - | nC | | | |
| Gate-drain charge | Qgd | - | 3.5 | - | nC | | | |
| *PULSED Body diode characteristics (source-drain characteristics) | | | | | | | | |
| Forward voltage | VSD | _ | - | -1.2 | V | Is=–1A, Vgs=0V | | |

Transistor





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